High Performance CMOS MEMS Oscillator for Automotive

Features

- · Automotive AEC-Q100 Qualified
- · Wide Frequency Range: 2.5 MHz to 170 MHz
- Very Low RMS Phase Jitter: <650 fs (typ.)
- High Stability: ±20 ppm, ±25 ppm, ±50 ppm
- · Wide Temperature Range:
 - Automotive Grade 1: -40°C to +125°C
 - Automotive Grade 2: -40°C to +105°C
 - Automotive Grade 3: -40°C to +85°C
- · Small Industry-Standard Footprints
 - 2.5 mm x 2.0 mm
 - 3.2 mm x 2.5 mm
 - 5.0 mm x 3.2 mm
 - 7.0 mm x 5.0 mm
- · Excellent Shock and Vibration Immunity
 - Qualified to MIL-STD-883
- · High Reliability
 - 20x Better MTF than Quartz Oscillators
- Supply Range of 2.25V to 3.63V
- Standby, Frequency Select, and Output Enable Functions
- · Lead-Free and RoHS-Compliant

Applications

- · Automotive Infotainment
- Automotive ADAS
- · In-Vehicle Networking, CAN Bus, Ethernet

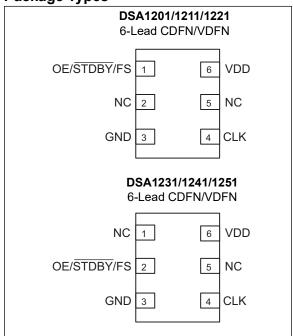
General Description

The DSA12x1 family of high performance oscillators utilizes the latest generation of silicon MEMS technology that reduces close-in noise and provides excellent jitter and stability over a wide range of supply voltages and temperatures. By eliminating the need for quartz or SAW technology, MEMS oscillators significantly enhance reliability and accelerate product development, while meeting stringent clock performance criteria for automotive applications.

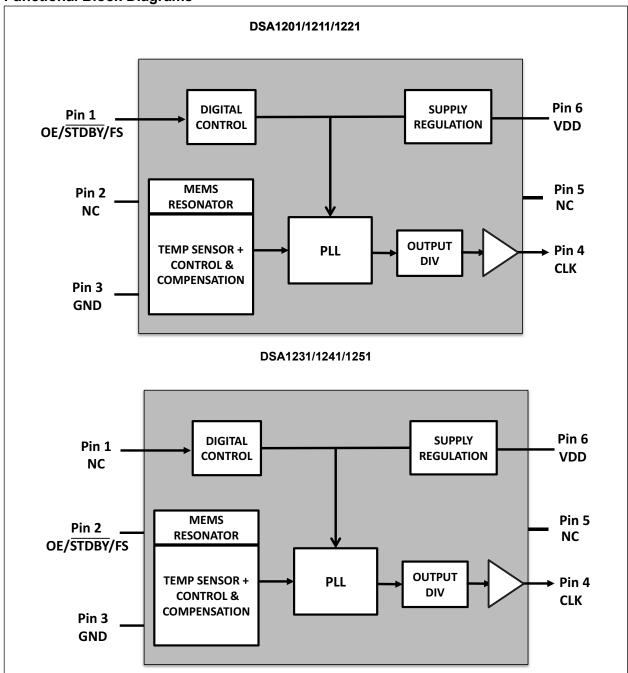
The DSA12x1 family features a control function on pin 1 or pin 2 that permits either a standby feature (complete power down when STDBY is low), output enable (output is tri-stated with OE low), or a frequency select (choice of two frequencies selected by FS high/low). See the Product Identification System section for detailed information.

All oscillators are available in industry-standard packages, including the small 2.5 mm x 2.0 mm, and are "drop-in" replacements for standard 4-pin and 6-pin CMOS quartz crystal oscillators.

Package Types



Functional Block Diagrams



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage	
Input Voltage	0.3V to V _{DD} + 0.3V
· ·	4 kV
• • •	400V
ESD Protection (CDM)	1.5 kV

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 2.5V ±10% or 3.3V ±10%; T_A = -40°C to +125°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Supply Voltage	V _{DD}	2.25		3.63	V	Note 1
Supply Current		_	27	_	mA	Output enabled, CMOS (no load), f _{OUT} = 100 MHz
Supply Current	l _{DD}	_	23	_	ША	Output disabled (tri-state), f _{OUT} = 100 MHz
Standby Current	I _{STDBY}	_	2.5	5	μΑ	Input pin = \overline{STDBY} = Asserted (V _{DD} = 3.3V)
		_		±20		Includes frequency variations due
Frequency Stability	Δf	_		±25	ppm	to initial tolerance, temp., and
		_		±50		power supply voltage
Aging	Δf	_	_	±5	ppm	First year @ 25°C
Aging	Δι	_	_	±1	ррііі	Per year after first year
Startup Time	t _{SU}	_	5.5	6	ms	From 90% V _{DD} to valid clock output, T = +25°C, Note 2
Input Logic Lovels	V _{IH}	0.75 x V _{DD}	_	_	V	Input logic high
Input Logic Levels	V _{IL}	_	_	0.25 x V _{DD}	V	Input logic low
Output Disable Time	t _{DA}	_	_	25	ns	Note 3
Output Enable Time		_	_	6	ms	STDBY
Output Enable Time	t _{EN}	_	_	350	ns	OE
Enable Pull-Up Resistor	_	_	1.5	_	ΜΩ	Pull-up resistor on pin 1, Note 4
Frequency	f ₀	2.5	_	170	MHz	_
Output Logic Level High	V _{OH}	0.8 x V _{DD}	_	_	V	I = ±12 mA
Output Logic Level Low	V _{OL}	_		0.2 x V _{DD}	V	1 - ±12 IIIA
Output Transition Time, Rise 20% to 80%;C _L =15 pF	t _R	_	1.2	_	ns	_
Output Transition Time, Fall 20% to 80%;C _L =15 pF	t _F	_	1.1	_	ns	_

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 2.5V ±10% or 3.3V ±10%; T_A = -40°C to +125°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Output Duty Cycle	SYM	45	_	55	%	_
Period Jitter, Peak-to-Peak	J _{PTP}	_	25	_	ps	f _{OUT} = 100 MHz
Cycle-to-Cycle Jitter, Peak	J _{CC}	_	22	_	ps	f _{OUT} = 100 MHz
Integrated Phase Noise (Random)	J _{PH}		0.65	_	ps _{RMS}	12 kHz to 20 MHz @ 100 MHz, T _A = +105°C

- **Note 1:** V_{DD} pin should be filtered with a 0.1 μF capacitor.
 - 2: t_{SU} is the time to 100 ppm stable output frequency after V_{DD} is applied and outputs are enabled.
 - 3: t_{DA}: See the Output Waveform and the Test Circuit sections for more information.
 - 4: Output is enabled if pad is floated (not connected).

TEMPERATURE SPECIFICATIONS Note 1

Parameters	Symbol	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Maximum Junction Temperature	TJ	_	_	+150	°C	_
Storage Temperature Range	T _S	- 55	_	+150	°C	_
Lead Temperature	_	_	_	+260	°C	Soldering, 40s

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above +150°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: DSA1201/1211/1221 PIN FUNCTION TABLE

Pin Number		1201	DSA	1211	DSA1221	
Pili Nulliber	Pin Name	Description	Pin Name	Description	Pin Name	Description
1	STDBY	Standby.	FS	Frequency select.	OE	Output enable.
2	NC	No connect.	NC	No connect.	NC	No connect.
3	GND	Power supply ground.	GND	Power supply ground.	GND	Power supply ground.
4	CLK	Clock output.	CLK	Clock output.	CLK	Clock output.
5	NC	No connect.	NC	No connect.	NC	No connect.
6	VDD	Power supply.	VDD	Power supply.	VDD	Power supply.

TABLE 2-2: DSA1231/1241/1251 PIN FUNCTION TABLE

DSA1231		\1231	DS	A1241	DSA1251		
Pin Number	Pin Number Pin Name		Pin Name	Description	Pin Name	Description	
1	NC	No connect.	NC	No connect.	NC	No connect.	
2	STDBY	Standby.	FS	Frequency select.	OE	Output enable.	
3	GND	Power supply ground.	GND	Power supply ground.	GND	Power supply ground.	
4	CLK	Clock output.	CLK	Clock output.	CLK	Clock output.	
5	NC	No connect.	NC	No connect.	NC	No connect.	

2.1 Standby

Complete power down when $\overline{\text{STDBY}}$ is low.

2.2 Frequency Select

Two frequencies may be chosen, selected by FS = High or Low. Please use the ClockWorks tool to customize frequencies.

2.3 Output Enable

Output buffers (only) are tri-stated when OE is low.

3.0 TERMINATION SCHEME

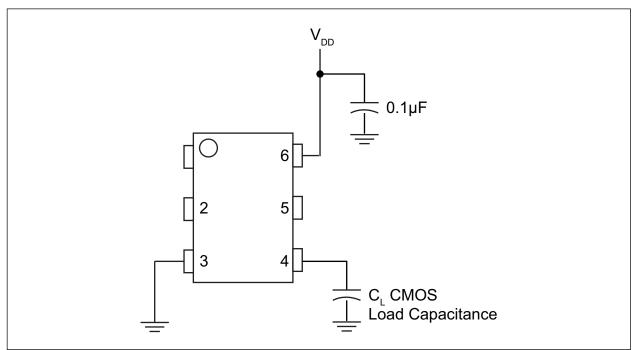


FIGURE 3-1: CMOS Termination.

4.0 OUTPUT WAVEFORM

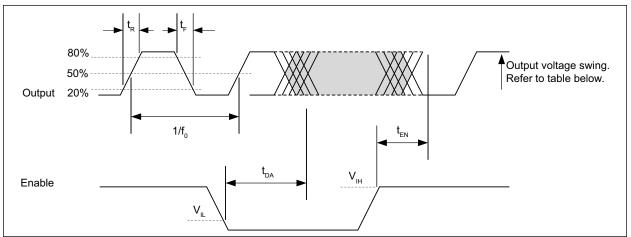


FIGURE 4-1: CMOS Output Waveform.

TABLE 4-1: OUTPUT VOLTAGE SWING BY LOGIC TYPE

Output Logic Protocol	Typical Peak-to-Peak Output Swing
CMOS	V_{OH} , V_{OL}

5.0 TEST CIRCUIT

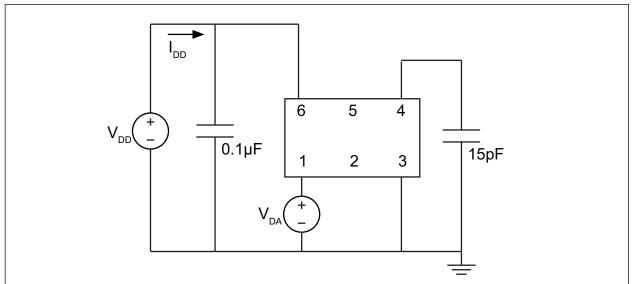


FIGURE 5-1: CMOS Test Circuit.

6.0 SOLDER REFLOW PROFILE

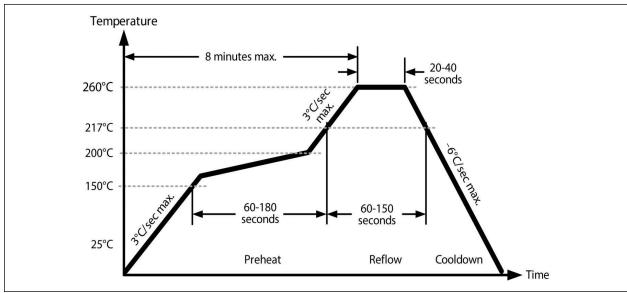


FIGURE 6-1: Solder Reflow Profile.

TABLE 6-1: SOLDER REFLOW

MSL 1 @ 260°C Refer to JSTD-020C						
Ramp-Up Rate (200°C to Peak Temp.)	3°C/sec. max.					
Preheat Time 150°C to 200°C	60 to 180 sec.					
Time Maintained above 217°C	60 to 150 sec.					
Peak Temperature	255°C to 260°C					
Time within 5°C of Actual Peak	20 to 40 sec.					
Ramp-Down Rate	−6°C/sec. max.					
Time 25°C to Peak Temperature	8 minutes max.					

7.0 BOARD LAYOUT (RECOMMENDED)

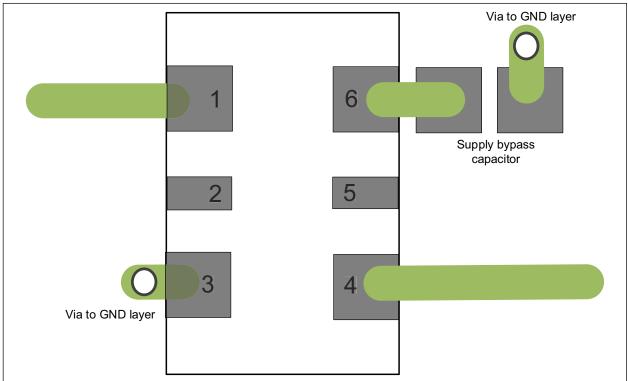


FIGURE 7-1: DSA12x1 Recommended Board Layout.

8.0 PHASE NOISE

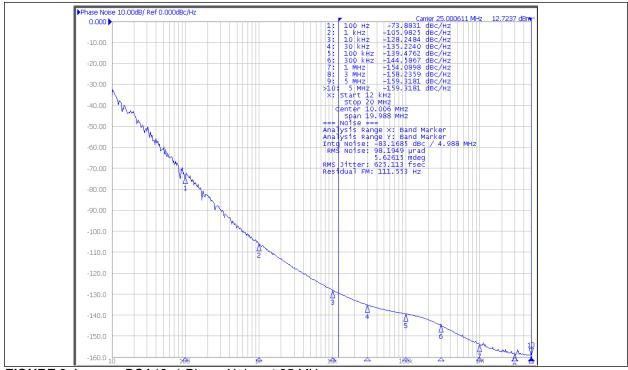


FIGURE 8-1: DSA12x1 Phase Noise at 25 MHz.

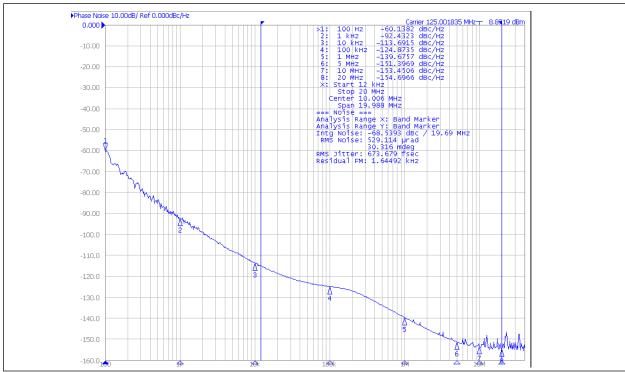


FIGURE 8-2: DSA12x1 Phase Noise at 125 MHz.

9.0 PACKAGING INFORMATION

9.1 Package Marking Information

6-Pin CDFN/VDFN*

XXXXXXXX DCPYYWW 0SSS Example

75M00000 DCP1723 0421

Legend: XX...X Product code or customer-specific information
Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

SSS Alphanumeric traceability code

e3 Pb-free JEDEC® designator for Matte Tin (Sn)

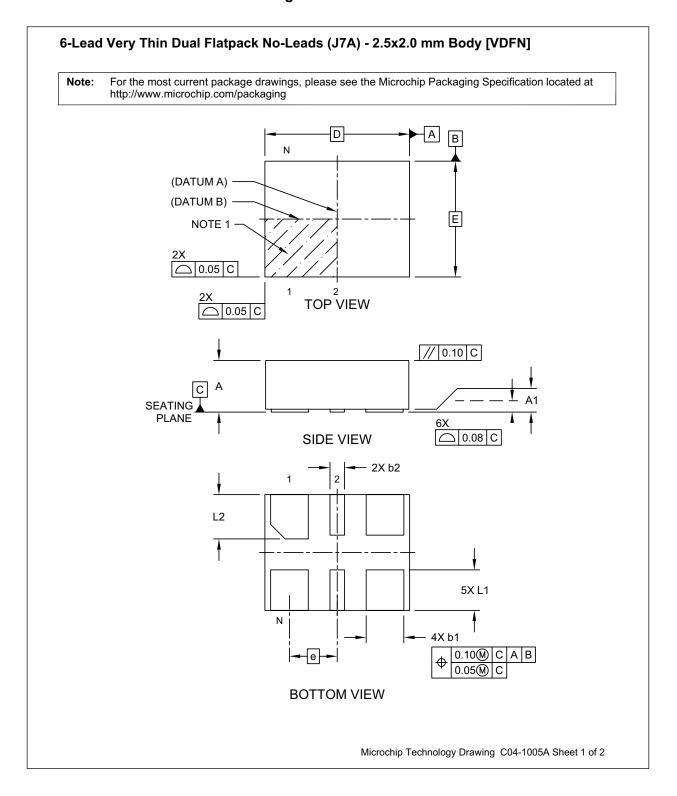
This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

ullet, lacktriangle, lacktriangle Pin one index is identified by a dot, delta up, or delta down (triangle mark).

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

Underbar (_) and/or Overbar (¯) symbol may not be to scale.

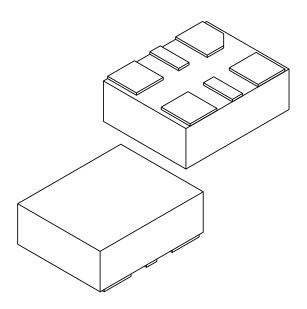
6-Lead VDFN 2.5 mm x 2.0 mm Package Outline and Recommended Land Pattern



Note:

6-Lead Very Thin Dual Flatpack No-Leads (J7A) - 2.5x2.0 mm Body [VDFN]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX	
Number of Terminals	N		6		
Pitch	е		0.825 BSC		
Overall Height	Α	0.80 0.85 0.90			
Standoff	A1	0.00	0.02	0.05	
Overall Length	D	2.50 BSC			
Overall Width	Е	2.00 BSC			
Terminal Width	b1	0.60	0.65	0.70	
Terminal Width	b2	0.20	0.25	0.30	
Terminal Length	L1	0.60	0.70	0.80	
Terminal Length	L2	0.665	0.765	0.865	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M $\,$

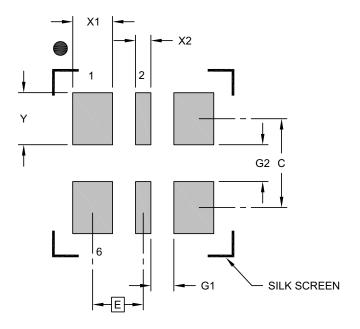
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1005A Sheet 2 of 2

6-Lead Very Thin Dual Flatpack No-Leads (J7A) - 2.5x2.0 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	E	0.825 BSC		
Contact Pad Width (X4)	X1			0.65
Contact Pad Width (X2)	X2			0.25
Contact Pad Length (X6)	Υ			0.85
Contact Pad Spacing	С		1.45	
Space Between Contacts (X4)	G1	0.38		
Space Between Contacts (X3)	G2	0.60		·

Notes:

- Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

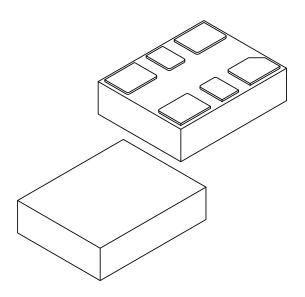
Microchip Technology Drawing C04-3005A

6-Lead VDFN 3.2 mm x 2.5 mm Package Outline and Recommended Land Pattern

6-Lead Very Thin Plastic Dual Flatpack No-Lead (H5A) - 3.2x2.5 mm Body [VDFN] Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging D Ν (DATUM A) (DATUM B) -NOTE 1 ○ 0.05 C **TOP VIEW** △ 0.05 C 0.10 C **SEATING PLANE** 0.08 SIDE VIEW 2X b2 NOTE 1 4X b1 **-**|e|-0.07M C A B 0.05M C **BOTTOM VIEW** Microchip Technology Drawing C04-1007A Sheet 1 of 2

6-Lead Very Thin Plastic Dual Flatpack No-Lead (H5A) - 3.2x2.5 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



		Units	MILLIMETERS				
	Dimension	Limits	MIN	NOM	MAX		
Number of Terminals		N		6	-		
Pitch		е	1.05 BSC				
Overall Height		Α	0.80 0.85 0.90				
Standoff		A1	0.00	0.02	0.05		
Overall Length		D	3.20 BSC				
Overall Width		Е		2.50 BSC			
Terminal Width		b1	0.85	0.90	0.95		
Terminal Width		b2	0.45	0.50	0.55		
Terminal Length		L	0.65	0.70	0.75		
Terminal Pullback		L1		0.10 REF			

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

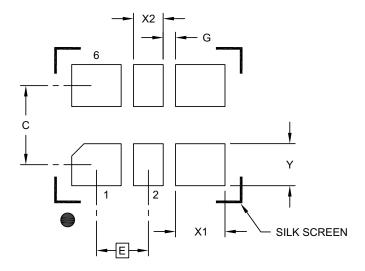
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1007A Sheet 2 of 2

Note:

6-Lead Very Thin Plastic Dual Flatpack No-Lead (H5A) - 3.2x2.5 mm Body [VDFN]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	MILLIMETERS			
Dimension	Dimension Limits			MAX	
Contact Pitch	Е		1.05 BSC		
Contact Pad Spacing	С		1.60		
Contact Pad Width (X4)	X1			1.00	
Contact Pad Width (X2)	X2			0.60	
Contact Pad Length (X6)	Υ			0.85	
Space Between Contacts (X4)	G1	0.25			

Notes:

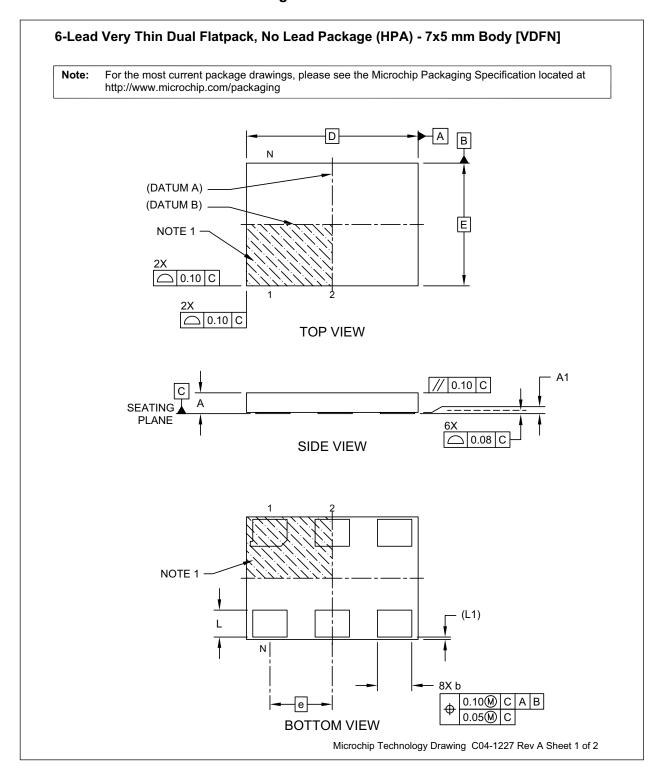
Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3007A

6-Lead CDFN 5.0 mm x 3.2 mm Package Outline and Recommended Land Pattern

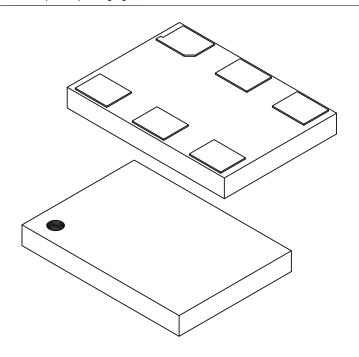
TITLE 6 LEAD CDFN 5.0x3.2mm COL PACKAGE OUTLINE & RECOMMENDED LAND PATTERN DRAWING # | CDFN5032-6LD-PL-1 UNIT MM 3.20±.05 3.20±.05 5.00±.05 $0.64 \pm .05$ 1.00±.10 1.20 REF Top View Bottom View Side View Recommended Land Pattern NOTE: * Power Supply Decoupling Capacitor is required in Recommended Land Pattern. Green shaded rectangles in Recommended Land Pattern are solder stencil opening. Red circles in Recommended Land Pattern are thermal VIA. For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

6-Lead VDFN 7.0 mm x 5.0 mm Package Outline and Recommended Land Pattern



6-Lead Very Thin Dual Flatpack, No Lead Package (HPA) - 7x5 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



		Units	MILLIMETERS				
	Dimension Limits		MIN	NOM	MAX		
Number of Terminals		N	6				
Pitch		е	2.54 BSC				
Overall Height		Α	0.80	0.85	0.90		
Standoff		A1	0.00	0.02	0.05		
Overall Length		D	7.00 BSC				
Overall Width		Е	5.00 BSC				
Terminal Width		b	1.30	1.40	1.50		
Terminal Length		L	1.00	1.10	1.20		
Pullback		L1	0.10 REF				

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

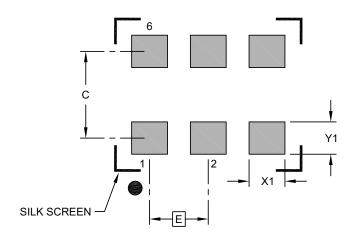
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1227 Rev A Sheet 2 of 2

6-Lead Very Thin Dual Flatpack, No Lead Package (HPA) - 7x5 mm Body [VDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units			MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX			
Contact Pitch	E	2.54 BSC					
Contact Pad Spacing	С		3.90				
Contact Pad Width (X6)	X1			1.55			
Contact Pad Length (X6)	Y1			1.40			

Notes:

- Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-3227 Rev A

APPENDIX A: REVISION HISTORY

Revision A (July 2020)

 Initial release of DSA12x1 as Microchip data sheet DS20006385A.

Revision B (August 2024)

 Updated values and conditions for Output Logic Levels, Output Transition Times, Period Jitter, and Cycle-to-Cycle Jitter in the Electrical Characteristics table.



NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

X	X	¥	X	<u>-X</u>	<u>xxxxxx</u>	X	<u>xxx</u>
		Temperature	Freq. Stabili	ty Outpu	it Frequency	Media Type	Automotive Suffix
DCA40:	Uinh Derferre	OMOS MEMS S	\:U-tf	Example	s:		
	Automotive		DSCIIIATOR FOR	a) DSA1	Pull-up, Cl	MOS Out	put, 7x5 VDFN,
-					•		
3 = 4 =	Pin 2 STDBY wit Pin 2 Frequency	n Pull-up Select with Pull-up		b) DSA12	with Pull-up, -40°C to +10	CMOS Ou 5°C, ±20 pp	tput, 3.2x2.5 VDFN, m, Frequency Select,
	O.W.O.G	and VDEN		c) DSA12	CMOS Outp	out, 5x3.2, 19.5 MHz	-40°C to +85°C, Output Frequency,
B = C =	5 mm x 3.2 mm (3.2 mm x 2.5 mn	6-Lead CDFN n 6-Lead VDFN		d) DSA1	Pull-up, CN -40°C to +10	MOS Outp 5°C, ±20 pp	out, 2.5x2 VDFN, m, 55.82 MHz Output
	-40°C to +105°C	(Automotive Grade	e 2)	e) DSA1	Pull-up, Cl -40°C to +85	MOS Out 5°C, ±50 pp	put, 7x5 VDFN, m, Frequency Select
1 =	±50 ppm			Automotiv	е		
				Note 1:	catalog part nur	mber descript	tion. This identifier is
xxMxxxxx xxxMxxxx	= <100 MHz = >100 MHz	Select			the device pack Sales Office for	age. Check v package ava	with your Microchip
T :	= 1,000/Reel						
		in which "XX" is as	ssigned by				
	DSA12: 0 = 1 = 2 = 3 = 4 = 5 = 1 = N = B = C = D = A = L = 1 = I = 2 = 3 = XMXXXXXX XXMXXXXX XXXMXXXXX XXXMXXXX XXXMXX XXXMXX XXXMXX XXXMXX XXXMXX XXXMXX XXXMX X	DSA12: High Performan Automotive 0 = Pin 1 STDBY with 1 = Pin 1 Pequency 2 = Pin 1 OE with Pu 3 = Pin 2 STDBY with 4 = Pin 2 Frequency 5 = Pin 2 OE with Pu 1 = CMOS N = 7 mm x 5 mm 6-l B = 5 mm x 3.2 mm 6 C = 3.2 mm x 2.5 mm D = 2.5 mm x 2 mm 6 C = 3.2 mm x 2 mm 6 C = 3.2 mm x 2 mm 6 C = 40°C to +105°C C C = 40°C to +105°C C C C C = 40°C to +85°C C C C C C C C C C C C C C C C C C C	DSA12: High Performance CMOS MEMS CAutomotive 0 = Pin 1 STDBY with Pull-up 1 = Pin 1 Frequency Select with Pull-up 2 = Pin 1 OE with Pull-up 3 = Pin 2 STDBY with Pull-up 4 = Pin 2 Frequency Select with Pull-up 5 = Pin 2 OE with Pull-up 1 = CMOS N = 7 mm x 5 mm 6-Lead VDFN B = 5 mm x 3.2 mm 6-Lead VDFN C = 3.2 mm x 2.5 mm 6-Lead VDFN C = 3.2 mm x 2.5 mm 6-Lead VDFN D = 2.5 mm x 2 mm 6-Lead VDFN A = -40°C to +125°C (Automotive Grad L = -40°C to +105°C (Automotive Grad L = -40°C to +85°C (Automotive Grade L = -40°C to +105°C (Automotive Grade	DSA12: High Performance CMOS MEMS Oscillator for Automotive 0 = Pin 1 STDBY with Pull-up 1 = Pin 1 Frequency Select with Pull-up 2 = Pin 1 OE with Pull-up 3 = Pin 2 STDBY with Pull-up 4 = Pin 2 Frequency Select with Pull-up 5 = Pin 2 OE with Pull-up 1 = CMOS N = 7 mm x 5 mm 6-Lead VDFN B = 5 mm x 3.2 mm 6-Lead VDFN C = 3.2 mm x 2.5 mm 6-Lead VDFN D = 2.5 mm x 2 mm 6-Lead VDFN A = -40°C to +125°C (Automotive Grade 1) L = -40°C to +105°C (Automotive Grade 2) I = -40°C to +85°C (Automotive Grade 3) 1 = ±50 ppm 2 = ±25 ppm 3 = ±20 ppm xMxxxxxx = <10 MHz xxMxxxxx = <10 MHz xxMxxxxx = <10 MHz cxxMxxxxx = <10 MHz cxxMxxxx = <10 MHz cxxMxxxxx = <10 MHz	DSA12: High Performance CMOS MEMS Oscillator for Automotive 0 = Pin 1 STDBY with Pull-up 1 = Pin 1 Frequency Select with Pull-up 2 = Pin 1 OE with Pull-up 3 = Pin 2 STDBY with Pull-up 5 = Pin 2 OE with Pull-up 1 = CMOS C = 3.2 mm x 5 mm 6-Lead VDFN B = 5 mm x 3.2 mm 6-Lead VDFN C = 3.2 mm x 2.5 mm 6-Lead VDFN D = 2.5 mm x 2 mm 6-Lead VDFN C = 3.2 mm x 2.5 mm 6-Lead VDFN D = 2.5 mm x 2 mm 6-Lead VDFN A = -40°C to +125°C (Automotive Grade 1) L = -40°C to +85°C (Automotive Grade 2) I = ±50 ppm 2 = ±25 ppm 3 = ±20 ppm Automotive XMxxxxx = <10 MHz xxMxxxxx = <10 MHz xxxMxxxxx = <100 MHz T = 1,000/Reel	DSA12:	DSA12:

Please visit the Microchip ClockWorks Configurator® website to configure the part number for customized frequency select settings.

http://clockworks.microchip.com/timing



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